

1A, 30V - 60V Surface Mount Schottky Barrier Rectifier

FEATURES

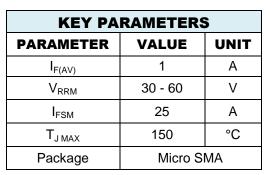
- AEC-Q101 qualified
- Very low profile typical height of 0.68mm
- Low power loss, high efficiency
- Ideal for automated placement
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

Δ	D	D	 C	Δ'	TI	n	N	S
_				_		u	14	J

- Converter
- Free wheeling
- LED lighting
- Adapters

MECHANICAL DATA

- Case: Micro SMA
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.006 g (approximately)











Micro SMA

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)							
PARAMETER	SYMBOL	SS13M	SS14M	SS16M	UNIT		
Marking code on the device		Α	В	С			
Repetitive peak reverse voltage	V_{RRM}	30	40	60	V		
Forward current	I _{F(AV)}	1		Α			
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	25		А			
Junction temperature	T_J	- 55 to +150		°C			
Storage temperature	T _{STG}	- 55 to +150		°C			

1 Version: N1810



THERMAL PERFORMANCE						
PARAMETER	SYMBOL	TYP.	UNIT			
Junction-to-lead Thermal Resistance	R _{OJL}	30	°C/W			
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	125	°C/W			
Junction-to-case thermal resistance	R _{eJC}	40	°C/W			

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
	SS13M	$I_F = 0.5A, T_J = 25$ °C	V _F	0.45	-	V
		$I_F = 1.0A, T_J = 25^{\circ}C$		0.52	0.55	V
	SS14M	$I_F = 0.5A, T_J = 125^{\circ}C$		0.35	-	V
Converse voltage new diede (1)		$I_F = 1.0A, T_J = 125^{\circ}C$		0.46	0.50	V
Forward voltage per diode (1)		$I_F = 0.5A, T_J = 25^{\circ}C$	V _F	0.51	-	V
	004014	$I_F = 1.0A, T_J = 25^{\circ}C$		0.64	0.68	V
	SS16M	$I_F = 0.5A, T_J = 125^{\circ}C$		0.46	-	V
		$I_F = 1.0A, T_J = 125^{\circ}C$		0.57	0.60	V
	SS13M SS14M	T _J = 25°C	I _R	5	50	μΑ
		T _J = 125°C		3	10	mA
Reverse current @ rated V _R		T _J = 150°C		5.3	-	mA
per diode (2)		T _J = 25°C	I _R	5	50	μA
	SS16M	T _J = 125°C		3	10	mA
		T _J = 150°C		6	-	mA
Junction capacitance	SS13M SS14M	1 MHz, V _R =4.0V	CJ	50	-	pF
	SS16M	, , ,		40	-	pF

Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION					
ORDERING CODE	PACKAGE	PACKING			
SS13MHRSG	Micro SMA	3000 / 7" Plastic reel			
SS14MHRSG	Micro SMA	3000 / 7" Plastic reel			
SS16MHRSG	Micro SMA	3000 / 7" Plastic reel			
SS13M RSG	Micro SMA	3000 / 7" Plastic reel			
SS14M RSG	Micro SMA	3000 / 7" Plastic reel			
SS16M RSG	Micro SMA	3000 / 7" Plastic reel			

Note: "H" means AEC-Q101 qualified



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Forward Current Derating Curve

1.2 AVERAGE FORWARD CURRENT (A) 1 8.0 0.6 0.4 0.2 **RESISTIVE OR** INDUCTIVE LOAD 0 0 25 50 75 100 125 150 LEAD TEMPERATURE (°C)

Fig.2 Typical Junction Capacitance

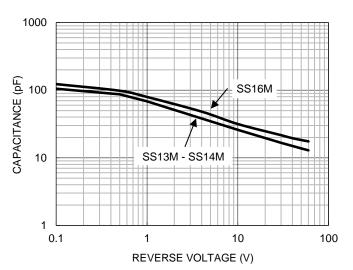
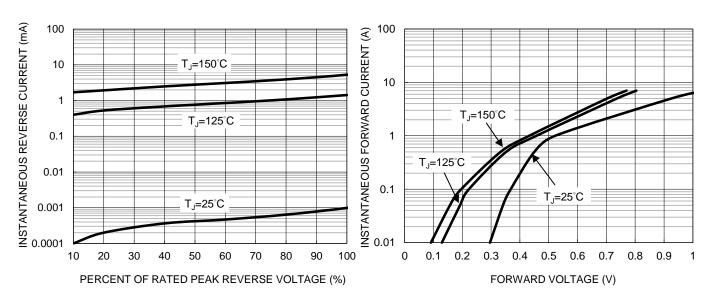


Fig.3 Typical Reverse Characteristics

Fig.4 Typical Forward Characteristics



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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.5 Typical Reverse Characteristics

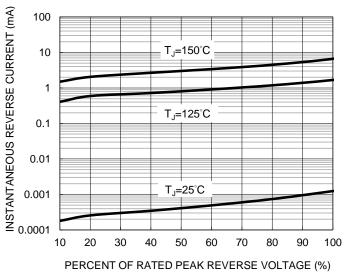


Fig.6 Typical Forward Characteristics

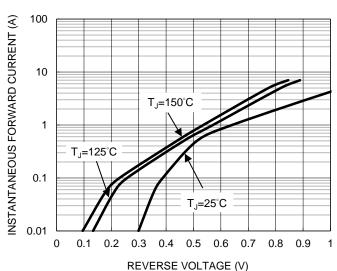


Fig.7 Maximum Forward Surge Current

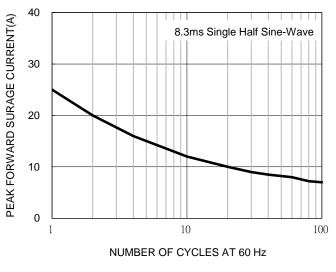
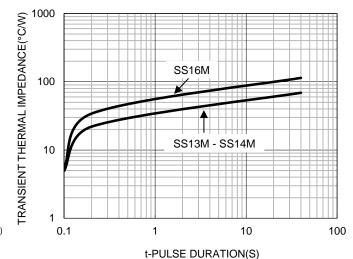


Fig.8 Typical Transient Thermal Impedance

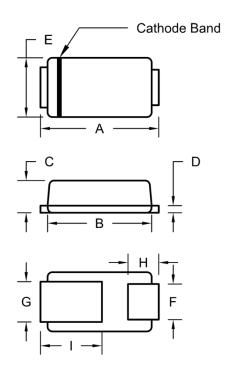


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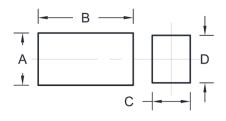
PACKAGE OUTLINE DIMENSIONS

Micro SMA



DIM	Unit	(mm)	Unit (inch)		
DIIVI	Min.	Max.	Min.	Max.	
Α	2.30	2.70	0.091	0.106	
В	2.10	2.30	0.083	0.091	
С	0.63	0.73	0.025	0.029	
D	0.10	0.20	0.004	0.008	
E	1.15	1.35	0.045	0.053	
F	0.65	0.85	0.026	0.034	
G	0.75	0.95	0.030	0.037	
Н	0.55	0.75	0.022	0.030	
I	1.10	1.50	0.043	0.059	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	1.10	0.043
В	2.00	0.079
С	0.80	0.031
D	1.00	0.039

MARKING DIAGRAM



P/N = Marking Code YW = Date Code



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